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National Semiconductor

April 1998

LMC660
CMOS Quad Operational Amplifier

General Description

The LMC660 CMOS Quad operational amplifier is ideal for operation from a single supply. It operates from +5V to +15V and features rail-to-rail output swing in addition to an input common-mode range that includes ground. Performance limitations that have plagued CMOS amplifiers in the past are not a problem with this design. Input V_{OS}, drift, and broadband noise as well as voltage gain into realistic loads (2 kΩ and 600Ω) are all equal to or better than widely accepted bipolar equivalents.

This chip is built with National's advanced Double-Poly Silicon-Gate CMOS process.

See the LMC662 datasheet for a dual CMOS operational amplifier with these same features.

Features

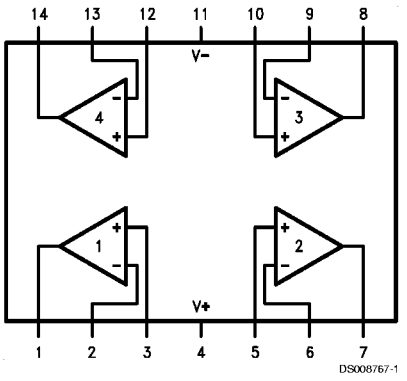
- Rail-to-rail output swing
- Specified for 2 kΩ and 600Ω loads
- High voltage gain: 126 dB
- Low input offset voltage: 3 mV
- Low offset voltage drift: 1.3 µV/°C
- Ultra low input bias current: 2 fA
- Input common-mode range includes V^-
- Operating range from +5V to +15V supply
- I_{SS} = 375 µA/amplifier; independent of V^+
- Low distortion: 0.01% at 10 kHz
- Slew rate: 1.1 V/µs
- Available in extended temperature range (−40°C to +125°C); ideal for automotive applications
- Available to Standard Military Drawing specification

Applications

- High-impedance buffer or preamplifier
- Precision current-to-voltage converter
- Long-term integrator
- Sample-and-Hold circuit
- Peak detector
- Medical instrumentation
- Industrial controls
- Automotive sensors

Connection Diagram

14-Pin DIP/SO



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Ordering Information

Package	Temperature Range				NSC Drawing	Transport Media
	Military −55˚C to +125˚C	Extended −40˚C +125˚C	Industrial −40˚C to +85˚C	Commercial 0˚C to +70˚C		
14-Pin Ceramic DIP	LMC660AMJ/883				J14A	Rail
14-Pin Small Outline		LMC660EM	LMC660AIM	LMC660CM	M14A	Rail Tape and Reel
14-Pin Molded DIP		LMC660EN	LMC660AIN	LMC660CN	N14A	Rail
14-Pin Side Brazed Ceramic DIP	LMC660AMD				D14E	Rail

Absolute Maximum Ratings (Note 3)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Differential Input Voltage	±Supply Voltage
Supply Voltage	16V
Output Short Circuit to V^+	(Note 12)
Output Short Circuit to V^-	(Note 1)
Lead Temperature	
(Soldering, 10 sec.)	260˚C
Storage Temp. Range	−65˚C to +150˚C
Voltage at Input/Output Pins	(V^+) + 0.3V, (V^-) − 0.3V
Current at Output Pin	±18 mA
Current at Input Pin	±5 mA
Current at Power Supply Pin	35 mA
Power Dissipation	(Note 2)
Junction Temperature	150˚C
ESD tolerance (Note 8)	1000V

Operating Ratings

Temperature Range	
LMC660AMJ/883, LMC660AMD	$-55˚C \le T_J \le +125˚C$
LMC660AI	$-40˚C \le T_J \le +85˚C$
LMC660C	$0˚C \le T_J \le +70˚C$
LMC660E	$-40˚C \le T_J \le +125˚C$
Supply Voltage Range	4.75V to 15.5V
Power Dissipation	(Note 10)
Thermal Resistance (θ_{JA}) (Note 11)	
14-Pin Ceramic DIP	90˚C/W
14-Pin Molded DIP	85˚C/W
14-Pin SO	115˚C/W
14-Pin Side Brazed Ceramic DIP	90˚C/W

DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25˚C. **Boldface** limits apply at the temperature extremes. V^+ = 5V, V^- = 0V, V_{CM} = 1.5V, V_O = 2.5V and R_L > 1M unless otherwise specified.

Parameter	Conditions	Typ (Note 4)	LMC660AMD LMC660AMJ/883	LMC660AI	LMC660C	LMC660E	Units
			Limit (Notes 4, 9)	Limit (Note 4)	Limit (Note 4)	Limit (Note 4)	
Input Offset Voltage		1	3	3	6	6	mV
			3.5	**3.3**	**6.3**	**6.5**	max
Input Offset Voltage Average Drift		1.3					µV/˚C
Input Bias Current		0.002	20				pA
			100	**4**	**2**	**60**	max
Input Offset Current		0.001	20				pA
			100	**2**	**1**	**60**	max
Input Resistance		>1					TeraΩ
Common Mode Rejection Ratio	$0V \le V_{CM} \le 12.0V$	83	70	70	63	63	dB
	V^+ = 15V		**68**	**68**	**62**	**60**	min
Positive Power Supply Rejection Ratio	$5V \le V^+ \le 15V$	83	70	70	63	63	dB
	V_O = 2.5V		**68**	**68**	**62**	**60**	min
Negative Power Supply Rejection Ratio	$0V \le V^- \le -10V$	94	84	84	74	74	dB
			82	**83**	**73**	**70**	min
Input Common-Mode Voltage Range	V^+ = 5V & 15V For CMRR ≥ 50 dB	−0.4	−0.1	−0.1	−0.1	−0.1	V
			0	**0**	**0**	**0**	max
		$V^+ - 1.9$	$V^+ - 2.3$	$V^+ - 2.3$	$V^+ - 2.3$	$V^+ - 2.3$	V
			$V^+ - 2.6$	**$V^+ - 2.5$**	**$V^+ - 2.4$**	**$V^+ - 2.6$**	min
Large Signal Voltage Gain	R_L = 2 kΩ (Note 5) Sourcing	2000	400	440	300	200	V/mV
			300	**400**	**200**	**100**	min
	Sinking	500	180	180	90	90	V/mV
			70	**120**	**80**	**40**	min
	R_L = 600Ω (Note 5) Sourcing	1000	200	220	150	100	V/mV
			150	**200**	**100**	**75**	min
	Sinking	250	100	100	50	50	V/mV
			35	**60**	**40**	**20**	min

DC Electrical Characteristics (Continued)

Unless otherwise specified, all limits guaranteed for T_J = 25˚C. **Boldface** limits apply at the temperature extremes. V^+ = 5V, V^- = 0V, V_{CM} = 1.5V, V_O = 2.5V and R_L > 1M unless otherwise specified.

Parameter	Conditions	Typ (Note 4)	LMC660AMD LMC660AMJ/883	LMC660AI	LMC660C	LMC660E	Units
			Limit (Notes 4, 9)	Limit (Note 4)	Limit (Note 4)	Limit (Note 4)	
Output Swing	V^+ = 5V	4.87	4.82	4.82	4.78	4.78	V
	R_L = 2 kΩ to $V^+/2$		**4.77**	**4.79**	**4.76**	**4.70**	min
		0.10	0.15	0.15	0.19	0.19	V
			0.19	**0.17**	**0.21**	**0.25**	max
	V^+ = 5V	4.61	4.41	4.41	4.27	4.27	V
	R_L = 600Ω to $V^+/2$		**4.24**	**4.31**	**4.21**	**4.10**	min
		0.30	0.50	0.50	0.63	0.63	V
			0.63	**0.56**	**0.69**	**0.75**	max
	V^+ = 15V	14.63	14.50	14.50	14.37	14.37	V
	R_L = 2 kΩ to $V^+/2$		**14.40**	**14.44**	**14.32**	**14.25**	min
		0.26	0.35	0.35	0.44	0.44	V
			0.43	**0.40**	**0.48**	**0.55**	max
	V^+ = 15V	13.90	13.35	13.35	12.92	12.92	V
	R_L = 600Ω to $V^+/2$		**13.02**	**13.15**	**12.76**	**12.60**	min
		0.79	1.16	1.16	1.45	1.45	V
			1.42	**1.32**	**1.58**	**1.75**	max
Output Current	Sourcing, V_O = 0V	22	16	16	13	13	mA
V^+ = 5V			**12**	**14**	**11**	**9**	min
	Sinking, V_O = 5V	21	16	16	13	13	mA
			12	**14**	**11**	**9**	min
Output Current	Sourcing, V_O = 0V	40	19	28	23	23	mA
V^+ = 15V			**19**	**25**	**21**	**15**	min
	Sinking, V_O = 13V	39	19	28	23	23	mA
	(Note 12)		**19**	**24**	**20**	**15**	min
Supply Current	All Four Amplifiers	1.5	2.2	2.2	2.7	2.7	mA
	V_O = 1.5V		**2.9**	**2.6**	**2.9**	**3.0**	max

AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25˚C. **Boldface** limits apply at the temperature extremes. V^+ = 5V, V^- = 0V, V_{CM} = 1.5V, V_O = 2.5V and R_L > 1M unless otherwise specified.

Parameter	Conditions	Typ (Note 4)	LMC660AMD LMC660AMJ/883	LMC660AI	LMC660C	LMC660E	Units
			Limit (Notes 4, 9)	Limit (Note 4)	Limit (Note 4)	Limit (Note 4)	
Slew Rate	(Note 6)	1.1	0.8	0.8	0.8	0.8	V/µs
			0.5	**0.6**	**0.7**	**0.4**	min
Gain-Bandwidth Product		1.4	**0.5**				MHz
Phase Margin		50					Deg
Gain Margin		17					dB
Amp-to-Amp Isolation	(Note 7)	130					dB
Input Referred Voltage Noise	F = 1 kHz	22					$nV/\sqrt{Hz}$
Input Referred Current Noise	F = 1 kHz	0.0002					$pA/\sqrt{Hz}$

AC Electrical Characteristics (Continued)

Unless otherwise specified, all limits guaranteed for T_J = 25˚C. **Boldface** limits apply at the temperature extremes. V^+ = 5V, V^- = 0V, V_{CM} = 1.5V, V_O = 2.5V and R_L > 1M unless otherwise specified.

Parameter	Conditions	Typ (Note 4)	LMC660AMD LMC660AMJ/883	LMC660AI	LMC660C	LMC660E	Units
			Limit (Notes 4, 9)	Limit (Note 4)	Limit (Note 4)	Limit (Note 4)	
Total Harmonic Distortion	F = 10 kHz, A_V = −10 R_L = 2 kΩ, V_O = 8 V_{PP} V^+ = 15V	0.01					%

Note 1: Applies to both single supply and split supply operation. Continuous short circuit operation at elevated ambient temperature and/or multiple Op Amp shorts can result in exceeding the maximum allowed junction temperature of 150˚C. Output currents in excess of ±30 mA over long term may adversely affect reliability.

Note 2: The maximum power dissipation is a function of $T_{J(max)}$, θ_{JA}, and T_A. The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(max)} - T_A)/\theta_{JA}$.

Note 3: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 4: Typical values represent the most likely parametric norm. Limits are guaranteed by testing or correlation.

Note 5: V^+ = 15V, V_{CM} = 7.5V and R_L connected to 7.5V. For Sourcing tests, 7.5V ≤ V_O ≤ 11.5V. For Sinking tests, 2.5V ≤ V_O ≤ 7.5V.

Note 6: V^+ = 15V. Connected as Voltage Follower with 10V step input. Number specified is the slower of the positive and negative slew rates.

Note 7: Input referred. V^+ = 15V and R_L = 10 kΩ connected to $V^+/2$. Each amp excited in turn with 1 kHz to produce V_O = 13 V_{PP}.

Note 8: Human body model, 1.5 kΩ in series with 100 pF.

Note 9: A military RETS electrical test specification is available on request. At the time of printing, the LMC660AMJ/883 RETS spec complied fully with the **boldface** limits in this column. The LMC660AMJ/883 may also be procured to a Standard Military Drawing specification.

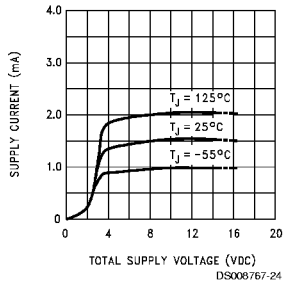
Note 10: For operating at elevated temperatures the device must be derated based on the thermal resistance θ_{JA} with $P_D = (T_J - T_A)/\theta_{JA}$.

Note 11: All numbers apply for packages soldered directly into a PC board.

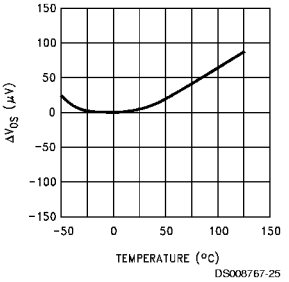
Note 12: Do not connect output to V^+ when V^+ is greater than 13V or reliability may be adversely affected.

Typical Performance Characteristics V_S = ±7.5V, T_A = 25˚C unless otherwise specified

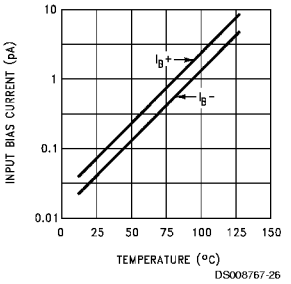
Supply Current vs Supply Voltage



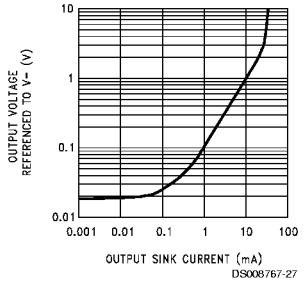
Offset Voltage



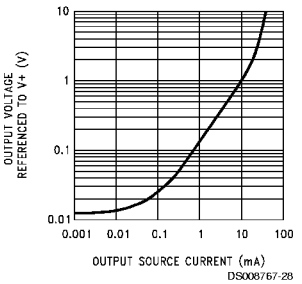
Input Bias Current



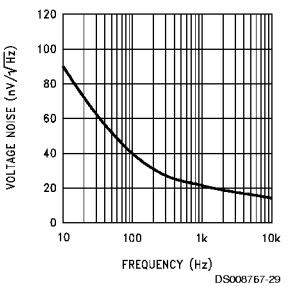
Output Characteristics Current Sinking



Output Characteristics Current Sourcing

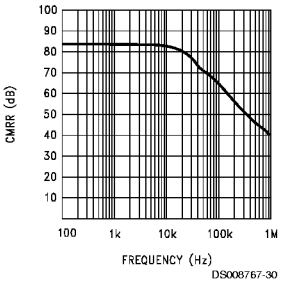


Input Voltage Noise vs Frequency

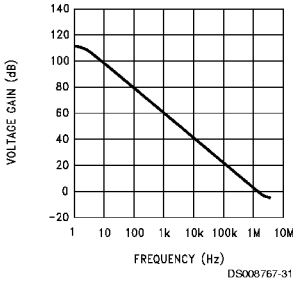


Typical Performance Characteristics V_S = ±7.5V, T_A = 25°C unless otherwise specified (Continued)

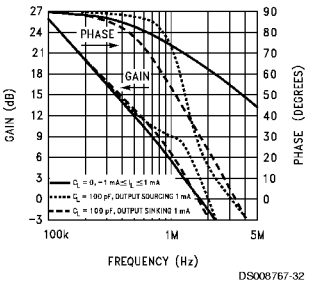
CMRR vs Frequency



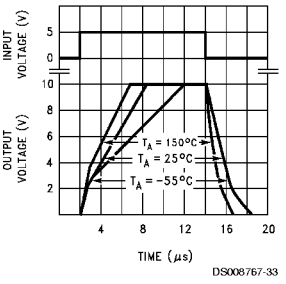
Open-Loop Frequency Response



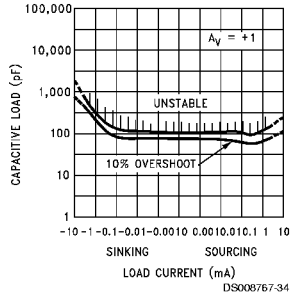
Frequency Response vs Capacitive Load



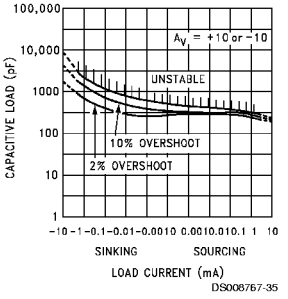
Non-Inverting Large Signal Pulse Response



Stability vs Capacitive Load



Stability vs Capacitive Load



Note 13: Avoid resistive loads of less than 500Ω, as they may cause instability.

Application Hints

Amplifier Topology

The topology chosen for the LMC660, shown in *Figure 1*, is unconventional (compared to general-purpose op amps) in that the traditional unity-gain buffer output stage is not used; instead, the output is taken directly from the output of the integrator, to allow rail-to-rail output swing. Since the buffer traditionally delivers the power to the load, while maintaining high op amp gain and stability, and must withstand shorts to either rail, these tasks now fall to the integrator.

As a result of these demands, the integrator is a compound affair with an embedded gain stage that is doubly fed forward (via C_f and Cff) by a dedicated unity-gain compensation driver. In addition, the output portion of the integrator is a push-pull configuration for delivering heavy loads. While sinking current the whole amplifier path consists of three gain stages with one stage fed forward, whereas while sourcing the path contains four gain stages with two fed forward.

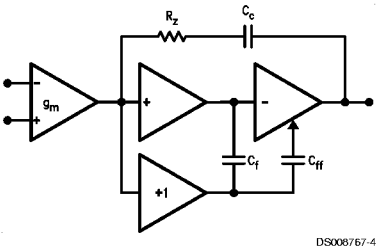


FIGURE 1. LMC660 Circuit Topology (Each Amplifier)

The large signal voltage gain while sourcing is comparable to traditional bipolar op amps, even with a 600Ω load. The gain while sinking is higher than most CMOS op amps, due to the additional gain stage; however, under heavy load (600Ω) the gain will be reduced as indicated in the Electrical Characteristics.

Compensating Input Capacitance

The high input resistance of the LMC660 op amps allows the use of large feedback and source resistor values without losing gain accuracy due to loading. However, the circuit will be especially sensitive to its layout when these large-value resistors are used.

Application Hints (Continued)

Every amplifier has some capacitance between each input and AC ground, and also some differential capacitance between the inputs. When the feedback network around an amplifier is resistive, this input capacitance (along with any additional capacitance due to circuit board traces, the socket, etc.) and the feedback resistors create a pole in the feedback path. In the following General Operational Amplifier circuit, *Figure 2* the frequency of this pole is

$$fp = \frac{1}{2\pi C_S R_P}$$

where C_S is the total capacitance at the inverting input, including amplifier input capcitance and any stray capacitance from the IC socket (if one is used), circuit board traces, etc., and R_P is the parallel combination of R_F and R_{IN}. This formula, as well as all formulae derived below, apply to inverting and non-inverting op-amp configurations.

When the feedback resistors are smaller than a few kΩ, the frequency of the feedback pole will be quite high, since C_S is generally less than 10 pF. If the frequency of the feedback pole is much higher than the "ideal" closed-loop bandwidth (the nominal closed-loop bandwidth in the absence of C_S), the pole will have a negligible effect on stability, as it will add only a small amount of phase shift.

However, if the feedback pole is less than approximately 6 to 10 times the "ideal" −3 dB frequency, a feedback capacitor, C_F, should be connected between the output and the inverting input of the op amp. This condition can also be stated in terms of the amplifier's low-frequency noise gain: To maintain stability a feedback capacitor will probably be needed if

$$\left(\frac{R_F}{R_{IN}} + 1\right) \leq \sqrt{6 \times 2\pi \times GBW \times R_F \times C_S}$$

where

$$\left(\frac{R_F}{R_{IN}} + 1\right)$$

is the amplifier's low-frequency noise gain and GBW is the amplifier's gain bandwidth product. An amplifier's low-frequency noise gain is represented by the formula

$$\left(\frac{R_F}{R_{IN}} + 1\right)$$

regardless of whether the amplifier is being used in inverting or non-inverting mode. Note that a feedback capacitor is more likely to be needed when the noise gain is low and/or the feedback resistor is large.

If the above condition is met (indicating a feedback capacitor will probably be needed), and the noise gain is large enough that:

$$\left(\frac{R_F}{R_{IN}} + 1\right) \geq 2\sqrt{GBW \times R_F \times C_S},$$

the following value of feedback capacitor is recommended:

$$C_F = \frac{C_S}{2\left(\frac{R_F}{R_{IN}} + 1\right)}$$

If

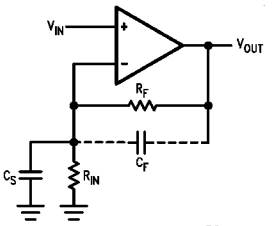
$$\left(\frac{R_F}{R_{IN}} + 1\right) < 2\sqrt{GBW \times R_F \times C_S}$$

the feedback capacitor should be:

$$C_F = \sqrt{\frac{C_S}{GBW \times R_F}}$$

Note that these capacitor values are usually significant smaller than those given by the older, more conservative formula:

$$C_F = \frac{C_S R_{IN}}{R_F}$$



C_S consists of the amplifier's input capacitance plus any stray capacitance from the circuit board and socket. C_F compensates for the pole caused by C_S and the feedback resistors.

FIGURE 2. General Operational Amplifier Circuit

Using the smaller capacitors will give much higher bandwidth with little degradation of transient response. It may be necessary in any of the above cases to use a somewhat larger feedback capacitor to allow for unexpected stray capacitance, or to tolerate additional phase shifts in the loop, or excessive capacitive load, or to decrease the noise or bandwidth, or simply because the particular circuit implementation needs more feedback capacitance to be sufficiently stable. For example, a printed circuit board's stray capacitance may be larger or smaller than the breadboard's, so the actual optimum value for C_F may be different from the one estimated using the breadboard. In most cases, the values of C_F should be checked on the actual circuit, starting with the computed value.

Capacitive Load Tolerance

Like many other op amps, the LMC660 may oscillate when its applied load appears capacitive. The threshold of oscillation varies both with load and circuit gain. The configuration most sensitive to oscillation is a unity-gain follower. See Typical Performance Characteristics.

The load capacitance interacts with the op amp's output resistance to create an additional pole. If this pole frequency is sufficiently low, it will degrade the op amp's phase margin so that the amplifier is no longer stable at low gains. As shown in *Figure 3*, the addition of a small resistor (50Ω to 100Ω) in series with the op amp's output, and a capacitor (5 pF to 10 pF) from inverting input to output pins, returns the phase margin to a safe value without interfering with lower-frequency circuit operation. Thus larger values of capacitance can be tolerated without oscillation. Note that in all cases, the output will ring heavily when the load capacitance is near the threshold for oscillation.

Application Hints (Continued)

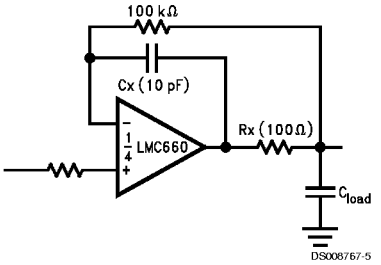


FIGURE 3. Rx, Cx Improve Capacitive Load Tolerance

Capacitive load driving capability is enhanced by using a pull up resistor to V^+ (*Figure 4*). Typically a pull up resistor conducting 500 µA or more will significantly improve capacitive load responses. The value of the pull up resistor must be determined based on the current sinking capability of the amplifier with respect to the desired output swing. Open loop gain of the amplifier can also be affected by the pull up resistor (see Electrical Characteristics).

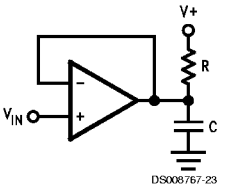


FIGURE 4. Compensating for Large Capacitive Loads with a Pull Up Resistor

PRINTED-CIRCUIT-BOARD LAYOUT FOR HIGH-IMPEDANCE WORK

It is generally recognized that any circuit which must operate with less than 1000 pA of leakage current requires special layout of the PC board. When one wishes to take advantage of the ultra-low bias current of the LMC662, typically less than 0.04 pA, it is essential to have an excellent layout. Fortunately, the techniques for obtaining low leakages are quite simple. First, the user must not ignore the surface leakage of the PC board, even though it may sometimes appear acceptably low, because under conditions of high humidity or dust or contamination, the surface leakage will be appreciable.

To minimize the effect of any surface leakage, lay out a ring of foil completely surrounding the LMC660's inputs and the terminals of capacitors, diodes, conductors, resistors, relay terminals, etc. connected to the op-amp's inputs. See *Figure 5*. To have a significant effect, guard rings should be placed on both the top and bottom of the PC board. This PC foil must then be connected to a voltage which is at the same voltage as the amplifier inputs, since no leakage current can flow between two points at the same potential. For example, a PC board trace-to-pad resistance of $10^{12}\Omega$, which is normally considered a very large resistance, could leak 5 pA if the trace were a 5V bus adjacent to the pad of an input. This would cause a 100 times degradation from the LMC660's actual performance. However, if a guard ring is held within 5 mV of the inputs, then even a resistance of $10^{11}\Omega$ would cause only 0.05 pA of leakage current, or perhaps a minor (2:1) degradation of the amplifier's performance. See *Figure 6a*, *Figure 6b*, *Figure 6c* for typical connections of guard rings for standard op-amp configurations. If both inputs are active and at high impedance, the guard can be tied to ground and still provide some protection; see *Figure 6d*.

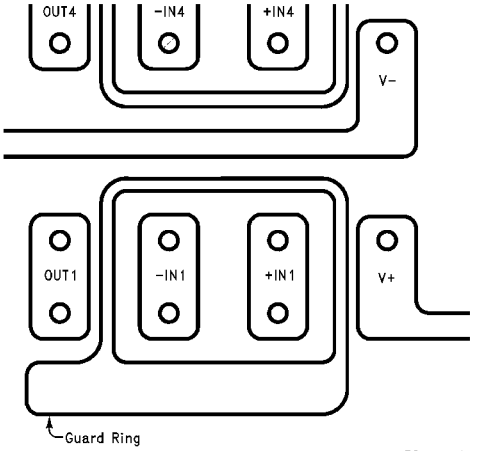
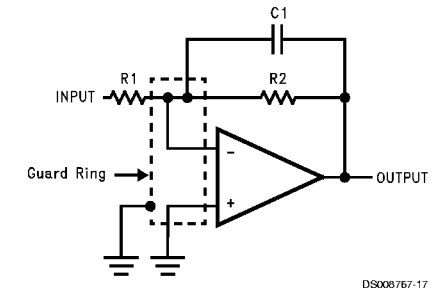
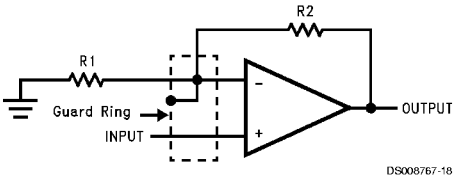


FIGURE 5. Example, using the LMC660, of Guard Ring in P.C. Board Layout

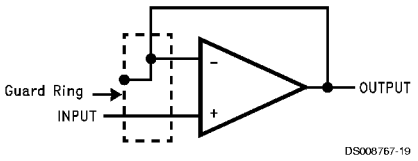
Application Hints (Continued)



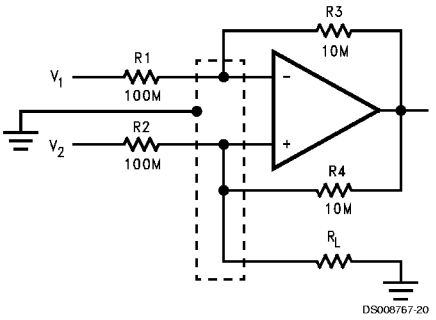
(a) Inverting Amplifier



(b) Non-Inverting Amplifier



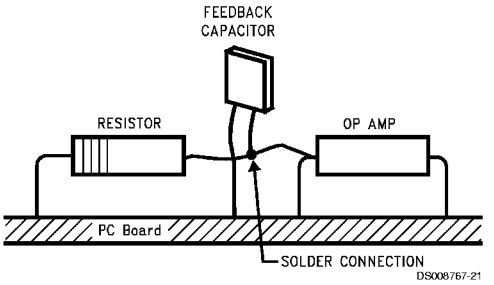
(c) Follower



(d) Howland Current Pump

FIGURE 6. Guard Ring Connections

The designer should be aware that when it is inappropriate to lay out a PC board for the sake of just a few circuits, there is another technique which is even better than a guard ring on a PC board: Don't insert the amplifier's input pin into the board at all, but bend it up in the air and use only air as an insulator. Air is an excellent insulator. In this case you may have to forego some of the advantages of PC board construction, but the advantages are sometimes well worth the effort of using point-to-point up-in-the-air wiring. See *Figure 7*.



(Input pins are lifted out of PC board and soldered directly to components. All other pins connected to PC board.)

FIGURE 7. Air Wiring

BIAS CURRENT TESTING

The test method of *Figure 8* is appropriate for bench-testing bias current with reasonable accuracy. To understand its operation, first close switch S2 momentarily. When S2 is opened, then

$$I_b^- = \frac{dV_{OUT}}{dt} \times C2.$$

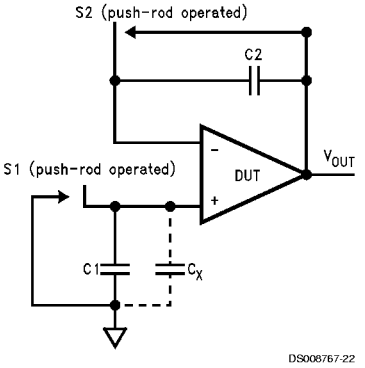


FIGURE 8. Simple Input Bias Current Test Circuit

A suitable capacitor for C2 would be a 5 pF or 10 pF silver mica, NPO ceramic, or air-dielectric. When determining the magnitude of I_b-, the leakage of the capacitor and socket must be taken into account. Switch S2 should be left shorted most of the time, or else the dielectric absorption of the capacitor C2 could cause errors.

Similarly, if S1 is shorted momentarily (while leaving S2 shorted)

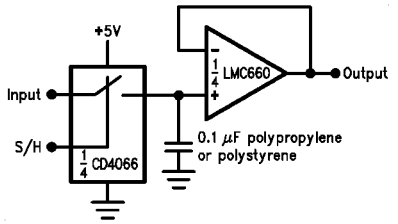
$$I_b^+ = \frac{dV_{OUT}}{dt} \times (C1 + C_x)$$

where C_x is the stray capacitance at the + input.

Typical Single-Supply Applications (V^+ = 5.0 VDC)

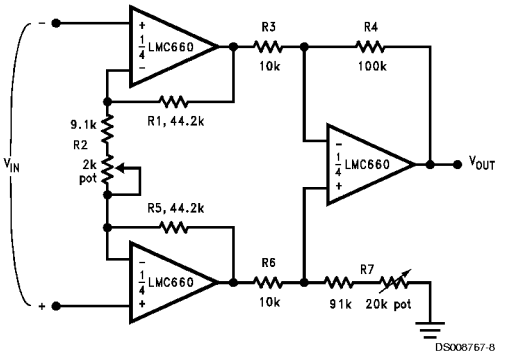
Additional single-supply applications ideas can be found in the LM324 datasheet. The LMC660 is pin-for-pin compatible with the LM324 and offers greater bandwidth and input resistance over the LM324. These features will improve the performance of many existing single-supply applications. Note, however, that the supply voltage range of the LMC660 is smaller than that of the LM324.

Low-Leakage Sample-and-Hold



DS008767-7

Instrumentation Amplifier



DS008767-8

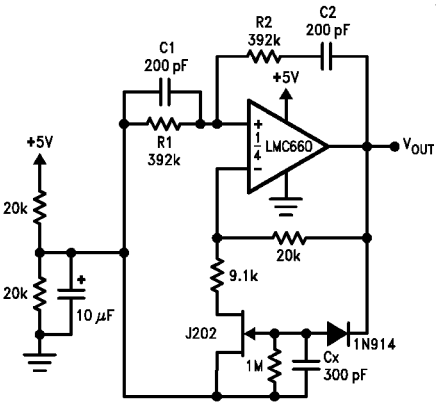
If R1 = R5, R3 = R6, and R4 = R7; then

$$\frac{V_{OUT}}{V_{IN}} = \frac{R2 + 2R1}{R2} \times \frac{R4}{R3}$$

$\therefore A_V \approx 100$ for circuit shown.

For good CMRR over temperature, low drift resistors should be used. Matching of R3 to R6 and R4 to R7 affect CMRR. Gain may be adjusted through R2. CMRR may be adjusted through R7.

Sine-Wave Oscillator



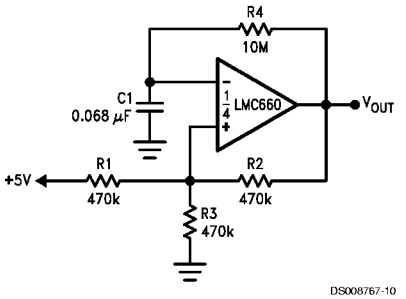
DS008767-9

Oscillator frequency is determined by R1, R2, C1, and C2:

fosc = 1/2πRC, where R = R1 = R2 and C = C1 = C2.

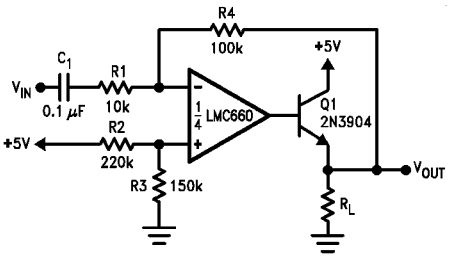
This circuit, as shown, oscillates at 2.0 kHz with a peak-to-peak output swing of 4.5V.

1 Hz Square-Wave Oscillator



DS008767-10

Power Amplifier

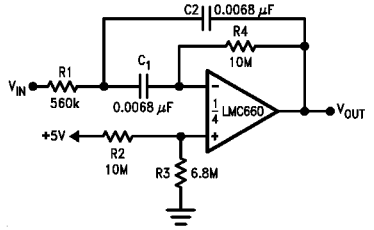


DS008767-11

Typical Single-Supply Applications

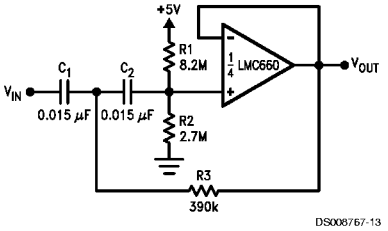
(V^+ = 5.0 VDC) (Continued)

10 Hz Bandpass Filter



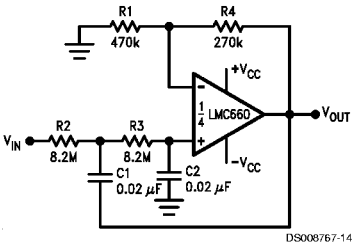
f_O = 10 Hz
Q = 2.1
Gain = −8.8

10 Hz High-Pass Filter



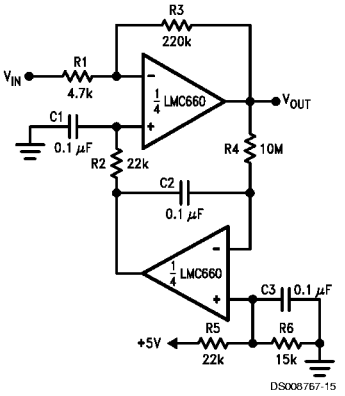
f_c = 10 Hz
d = 0.895
Gain = 1
2 dB passband ripple

1 Hz Low-Pass Filter (Maximally Flat, Dual Supply Only)



f_c = 1 Hz
d = 1.414
Gain = 1.57

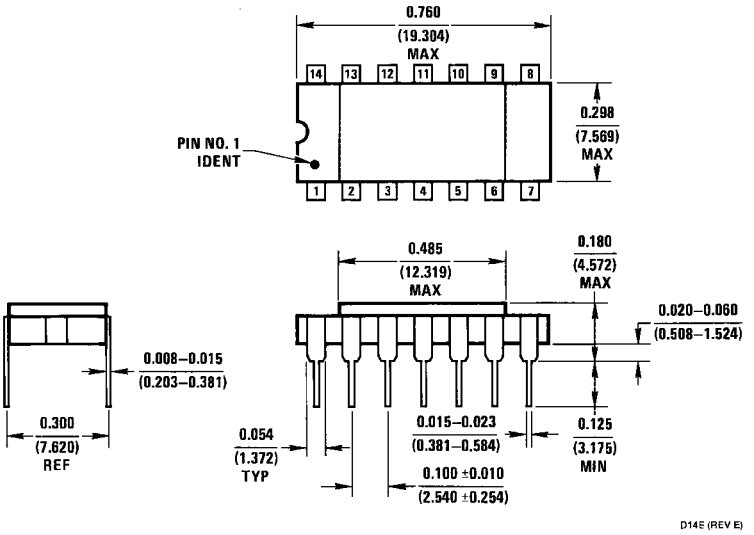
High Gain Amplifier with Offset Voltage Reduction



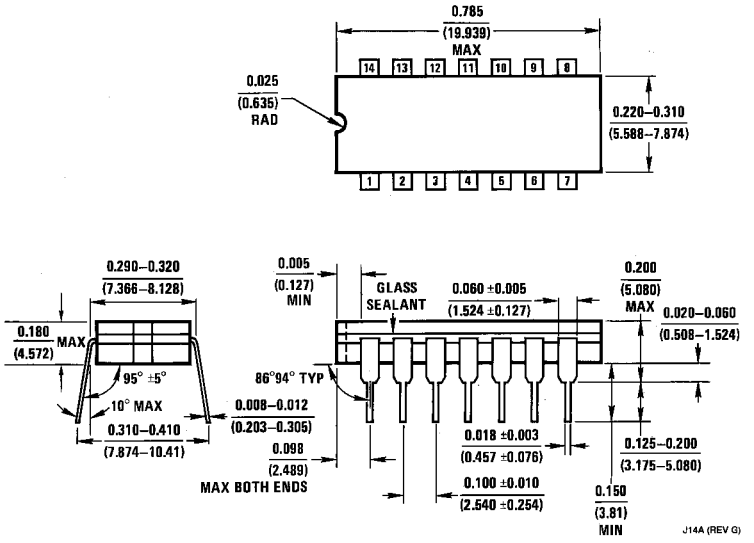
Gain = −46.8

Output offset voltage reduced to the level of the input offset voltage of the bottom amplifier (typically 1 mV).

Physical Dimensions inches (millimeters) unless otherwise noted

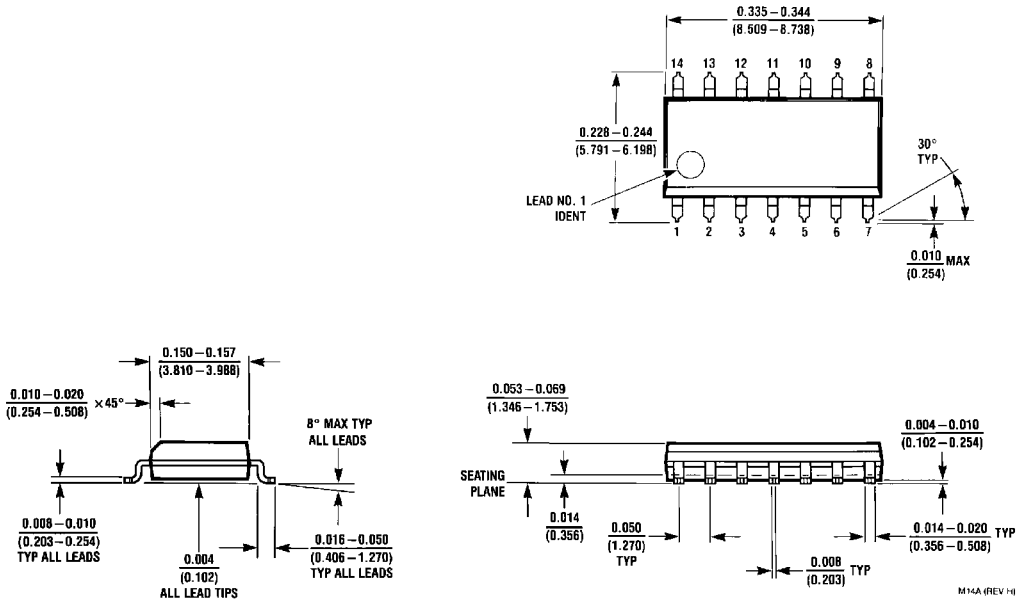


14-Lead Hermetic Dual-In-Line Package (D)
Order Number LMC660AMD
NS Package Number D14E

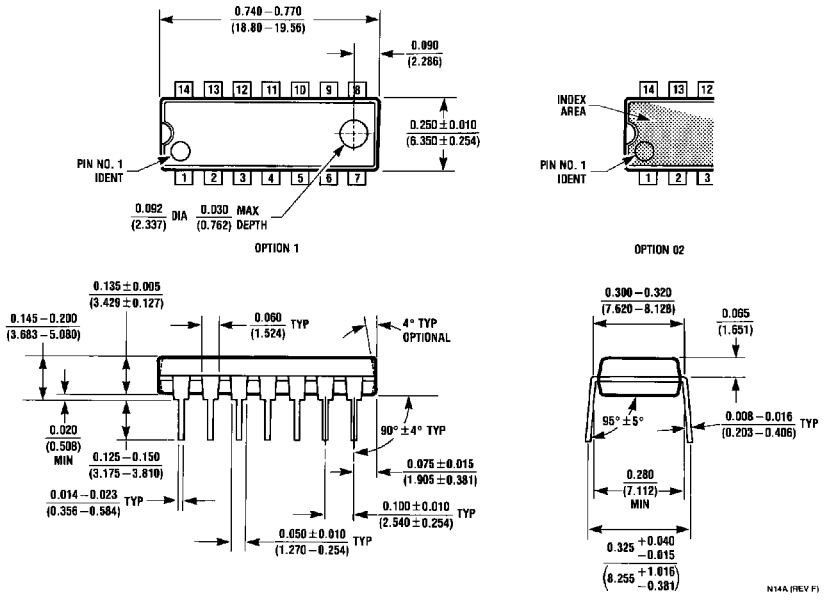


14-Lead Ceramic Dual-In-Line Pkg. (J)
Order Number LMC660AMJ/883
NS Package Number J14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



Small Outline Dual-In-Line Pkg. (M)
Order Number LMC660AIM, LMC660CM or LMC660EM
NS Package Number M14A



Molded Dual-In-Line Pkg. (N)
Order Number LMC660AIN, LMC660CN or LMC660EN
NS Package Number N14A

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